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### **Product Specifications**

July 1997

### Features

- **High Gain**
- □ +34 dBm Power Output
- □ Proprietary Power FET Process
- □ >45% Linear Power Added Efficiency
- □ +29 dBm with 30 dBc Third Order Products
- □ Surface Mount SO-8 Power Package

### Applications

- **D** PCS/PCN Base Stations and Terminals
- □ Wireless Local Loop

### Description

The CFK2162-P3 is a high-gain FET intended for driver amplifier applications in high-power systems, and output stage usage in medium power applications at power levels up to +34 dBm. The device is easily matched and provides excellent linearity at 2 Watts. Manufactured in Celeritek's proprietary

**Specifications** (TA =  $25^{\circ}$ C) The following specifications are guaranteed at room temperature in Celeritek test fixture at 1.95 GHz.

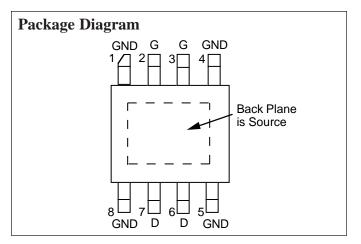
Parameters	Conditions	Min	Тур	Max	Units
$\overline{V_d} = 8V, I_d =$	= 800 mA (Quiescent)				
P-1dB		33.0	34.0	_	dBm
SSG		13.0	14.0		dB
<b>3rd Order</b> <b>Products</b> <sup>(1)</sup>		26	30		dBc
Efficiency	@ P1dB	_	43	_	%
$\overline{\mathbf{V}_{\mathbf{d}} = 5\mathbf{V}, \mathbf{I}_{\mathbf{d}} = }$	= 350 mA (Quiescent)				
P-1dB		—	30.0	_	dBm
SSG			11.0		dB
$V_d = 5V, I_d = 1200 \text{ mA} \text{ (Quiescent)}$					
P-1dB			32.5		dBm
SSG		_	12.0	—	dB

Parameters	Conditions	Min	Тур	Max	Units
g <sub>m</sub>	Vds = 2.0V, Vgs = 0V	—	1700	_	mS
Idss	Vds = 2.0V, Vgs = 0V		2.8		A
Vp	Vds = 3.0V, Ids = 65 mA		-1.8		Volts
$\overline{BV_{GD}}(3)$	Igd = 6.5 mA	18	20		Volts
$\Theta_{JL}(2)$	@150°C TCH		10		°C/W

#### Notes:

- 1. Sum to two tones with 1 MHz spacing = 29 dBm.
- 2. See thermal considerations information on page 4.
- 3. Max  $(+V_d)$  and  $(-V_g)$  under linear operation. Max potential difference across the device in RF compression  $(2V_d + |-V_g|)$  not to exceed the minimum breakdown voltage  $(V_{br})$  of +18V.

## 1.8 to 2.0 GHz +34 dBm Power GaAs FET

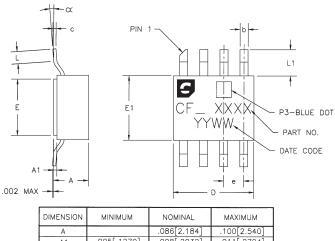


power FET process, this device is assembled in an industry standard surface mount SO-8 power package that is compatible with high volume, automated board assembly techniques.

#### **Absolute Maximum Ratings**

Parameter	Symbol	Rating
Drain-Source Voltage	V <sub>DS</sub>	12V <sup>(3)</sup>
Gate-Source Voltage	VGS	-5V
Drain Current	IDS	Idss
Continuous Dissipation	PT	10W
Channel Temperature	TCH	175°C
Storage Temperature	TSTG	-65°C to +175°C

### **SO-8** Power Package Physical Dimensions



A		.086[2.184]	.100[2.540]
A1	.005[.1270]	.008[.2032]	.011[.2794]
b	.017[.4318]	.020[.5080]	.023[.5842]
C.	.007[.1778]	.008[2032]	.009[.2286]
D	.195[4.953]	.200[5.080]	.205[5.207]
E	.135[3.429]	.140[3.556]	.145[3.683]
E1	.155[3.937]	.160[4.064]	.165[4.191]
e		.050[1.270]	
L	.020[.5080]		.040[1.016]
L1	.055[1.397]	.065[1.651]	.075[1.905]
α	0.		8'

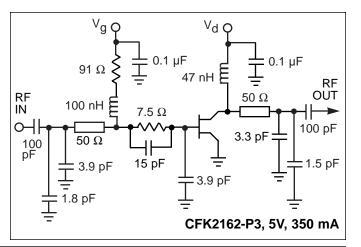
DIMENSIONS IN INCHES [MILIMETERS]

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<b>Typical Scattering Parameters</b>		$(TA = 25^{\circ}C, Vds = 5 V, Ids = 350 mA)$						
Frequency	S.	11	S <sub>2</sub>	1	S <sub>12</sub>		S <sub>2</sub>	2
(GHz)	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
0.6	0.946	-162.45	4.973	86.73	0.017	11.14	0.739	172.95
1.0	0.946	-176.06	2.885	73.75	0.018	9.37	0.748	169.73
1.1	0.946	-177.58	2.623	71.82	0.018	6.8	0.747	169.56
1.2	0.945	-178.58	2.424	69.66	0.019	6.59	0.746	169.16
1.3	0.944	-179.55	2.27	67.7	0.019	6.53	0.742	168.8
1.4	0.942	179.53	2.154	65.68	0.02	7.04	0.739	168.03
1.5	0.938	178.31	2.055	63.25	0.02	4.93	0.73	167.15
1.6	0.935	176.89	1.982	60.53	0.021	4.08	0.722	165.76
1.7	0.931	174.99	1.923	57.74	0.023	3.37	0.714	164.09
1.8	0.927	172.61	1.873	54.47	0.023	1.6	0.707	161.84
1.9	0.922	169.71	1.828	50.82	0.023	-0.79	0.70	158.98
2.0	0.918	166.09	1.777	46.63	0.025	-1.23	0.694	155.54
2.1	0.914	161.9	1.722	42.23	0.024	-4.64	0.69	151.93
2.2	0.912	157.79	1.664	37.59	0.026	-9.26	0.689	148.15
3.0	0.941	132.34	1.033	10.11	0.022	-27.73	0.76	128.69
3.5	0.957	134.66	0.803	6.12	0.02	-21.78	0.787	132.92
4.0	0.94	138.76	0.803	1.66	0.023	-20.57	0.74	136.51
			$(TA = 25^{\circ})$	,	7, Ids = 1200 mA)			
0.6	0.95	-165	5.311	84.94	0.014	13.61	0.747	17.19
1.0	0.951	-177.94	3.044	72.23	0.014	14.39	0.749	168.92
1.3	0.951	178.92	2.391	66.48	0.015	13.62	0.741	167.98
1.4	0.949	177.92	2.272	64.41	0.015	14.21	0.734	167.24
1.5	0.946	176.83	2.169	61.99	0.016	14.13	0.728	166.28
1.6	0.943	175.5	2.09	59.58	0.017	12.30	0.72	165.01
1.7	0.939	173.67	2.029	56.57	0.017	12.06	0.712	163.24
1.8	0.935	171.39	1.98	53.44	0.018	10.27	0.703	161.07
1.9	0.931	168.6	1.93	49.72	0.019	5.75	0.696	158.27
2.0	0.929	165.15	1.88	45.76	0.02	7.43	0.69	154.9
2.1	0.925	161.29	1.822	41.44	0.02	4.37	0.686	151.32
2.2	0.924	157.02	1.757	36.86	0.021	2.36	0.687	147.44
3.0	0.947	131.72	1.09	9.25	0.018	-17.77	0.757	127.79
3.5	0.961	133.41	0.853	4.59	0.017	-13.03	0.779	131.26
4.0	0.945	137.83	0.85	0.36	0.021	-8.72	0.73	134.73
			·	,	V, Ids = 800 mA)			
0.6	0.941	-164.65	5.654	83.55	0.015	10.74	0.676	174.61
1.0	0.947	-177.32	3.25	70.11	0.015	8.2	0.688	171.96
1.3	0.945	179.49	2.535	63.48	0.015	7.84	0.684	171.67
1.4	0.944	178.52	2.397	61.32	0.016	8.5	0.68	171.06
1.5	0.941	177.34	2.85	58.65	0.016	9.62	0.674	170.41
1.6	0.939	175.87	2.192	55.97	0.017	5.99	0.666	169.31
1.7	0.934	174.02	2.123	52.85	0.017	6.55	0.658	167.71
1.8	0.93	171.59	2.058	49.6	0.018	6.89	0.652	165.68
1.9 2.0	0.927 0.923	168.63	2.006	45.54	0.019 0.019	3.81	0.644	163.07
2.0 2.1	0.923 0.919	165.04 160.94	1.990 1.885	41.52 36.76	0.019	-1.07 -1.68	0.639 0.635	159.85 156.23
2.1 2.2	0.919 0.917			30.70 32.35	0.02	-1.68 -2.32		
2.2 3.0	0.917 0.944	156.65 131.73	1.714 1.116	32.35 3.58	0.02	-2.52 -21.43	0.636 0.722	152.38 132.33
		131.73	0.857	5.58 -1.39	0.018			
3.5 4.0	$0.96 \\ 0.942$	134.09	0.857	-6.32	0.016	-16.54 -10.57	0.762 0.723	136.36 140.71
4.0	0.742	137.70	0.041	-0.52	0.02	-10.57	0.725	140./1

**RF Match** Data shown in the performance graphs was taken in the test circuits shown at right and on page 3. Layout is important for proper operation. Phase length of input and output  $50\Omega$  line varies as a function of exact desired frequency of operation. Output shunt inductor effects output performance. Celeritek recommends the use of a high impedance printed inductor Lambda/4 in length. Please contact the factory for an evaluation board and/or more detailed application support.





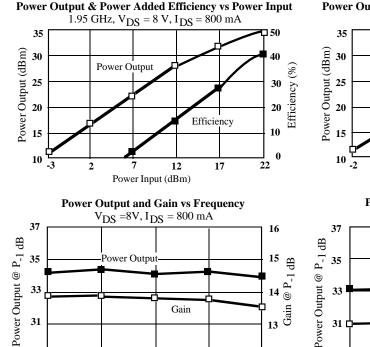
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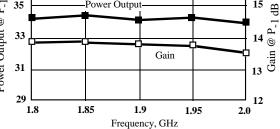
# **CFK2162-P3**

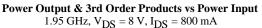
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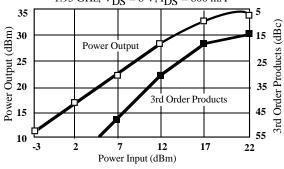
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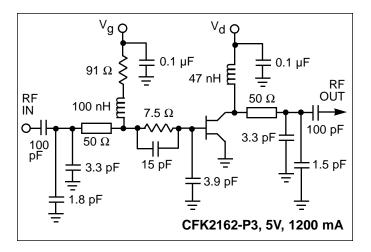
### **Typical Performance**

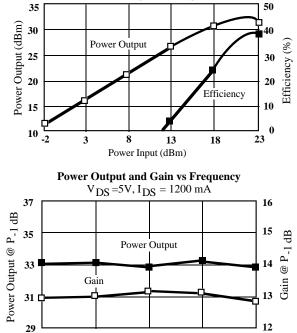












 $1.95 \text{ GHz}, \text{V}_{\text{DS}} = 5 \text{ V}, \text{I}_{\text{DS}} = 1.2 \text{ A}$ 

Frequency, GHz Power Output & 3rd Order Products vs Power Input

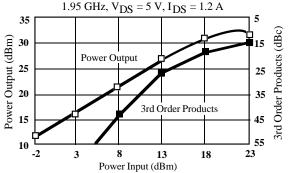
1.9

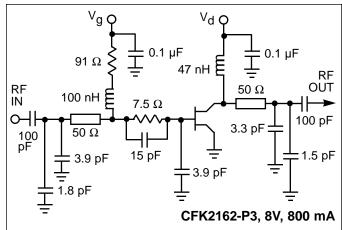
1.95

2.0

1.8

1.85





Power Output & Power Added Efficiency vs Power Input

### **Thermal Considerations**

The data shown was taken on a 31 mil thick FR-4 board with 1 ounce copper on both sides. The board was mounted to a baseplate with 3 screws as shown. The screws bring the top side copper temperature to the same value as the baseplate. The thermal resistance to the indicated reference lead,  $\Theta_{IL}$ , is 10°C/W. The thermal resistance to the reference screw is 12°C/W.

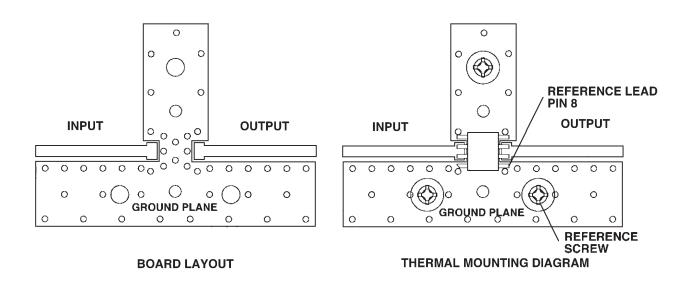
1. Use 1 or 2 ounce copper if possible.

2. Solder all eight leads of the CFK2162-P3 package to the appropriate electrical connection.

3. Solder the copper pad on the backside of the CFK2162-P3 package to the ground plane.

4. Use a large ground pad area with many plated through-holes as shown.

5. If possible, use at least one screw no more than 0.2 inches from the CFK2162-P3 package to provide a low thermal resistance path to the baseplate of the package.



### **Ordering Information**

The CFK2162-P3 power stage is available in a SO-8 surface mount package. Devices are available in tape and reel. Ordering part numbers are listed.

Part Number for Ordering	Function
CFK2162-P3	1.8 - 2.0 GHz Power Stage
CFK2162-P3-000T	1.8 - 2.0 GHz Power Stage

<u>Package</u> SO-8 surface mount power package SO-8 surface mount power package in tape and reel

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